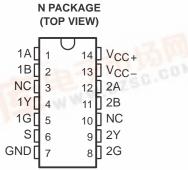
查询SN75207B供应商

捷多邦,专业PCB打样工厂,24小时加急出货 SN75207B DUAL SENSE AMPLIFIER FOR MOS MEMORIES OR DUAL HIGH-SENSITIVITY LINE RECEIVERS SLLS096C – JULY 1973 – REVISED MARCH 1997

- Plug-In Replacement for SN75107A and SN75107B With Improved Characteristics
- ±10-mV Input Sensitivity
- TTL-Compatible Circuitry
- Standard Supply Voltages . . . ±5 V
- Differential Input Common-Mode Voltage Range of ±3 V
- Strobe Inputs for Channel Selection
- Totem-Pole Outputs
- SN75207B Has Diode-Protected Input Stage for Power-Off Condition
- Sense Amplifier for MOS Memories
- Dual Comparator
- High-Sensitivity Line Receiver

description





The SN75207B is a terminal-for-terminal replacement for the SN75107B. The improved input sensitivity makes it more suitable for MOS memory sense amplifiers and can result in faster memory cycles. Improved sensitivity also makes it more useful in line-receiver applications by allowing use of longer transmission line lengths. The SN75207B features a TTL-compatible, active-pullup output.

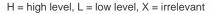
Input protection diodes are in series with the collectors of the differential-input transistors of the SN75207B. These diodes are useful in certain party-line systems that may have multiple V_{CC+} power supplies and may be operated with some of the V_{CC+} supplies turned off. In such a system, if a supply is turned off and allowed to go to ground, the equivalent input circuit connected to that supply would be as follows:



This would be a problem in specific systems that might have the transmission lines biased to some potential greater than 1.4 V.

This device is characterized for operation from 0°C to 70°C.

FUNCTION TABLE							
DIFFERENTIAL INPUTS	STROBES		OUTPUT				
A–B	G	S	Y				
$V_{ID} \ge 10 \text{ mV}$	Х	Х	Н				
–10 mV < V _{ID} < 10 mV	Х	L	н				
	L	Х	н				
	н	Н	Indeterminate				
N.073	Х	L	Н				
$V_{ID} \le -10 \text{ mV}$	L	Х	н				
	Н	Н	L				

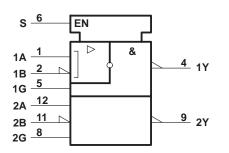




Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

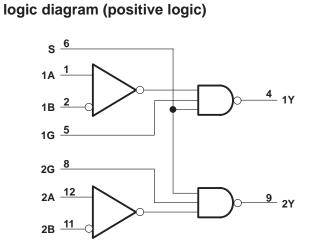


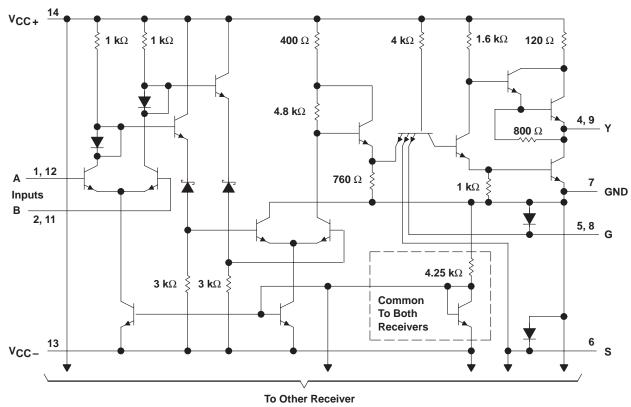
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

schematic (each receiver)





Resistor values shown are nominal.

design characteristics

The SN75207B line receivers/sense amplifiers are TTL-compatible, dual circuits intended for use in high-speed, data-transmission systems or MOS memory systems. They are designed to detect low-level differential signals in the presence of common-mode noise and variations of temperature and supplies. The dc specifications reflect worst-case conditions of temperature, supply voltages, and input voltages.

The input common-mode voltage range is ± 3 V. This is adequate for application in most systems. In systems with requirements for greater common-mode voltage range, input attenuators may be used to decrease the noise to an acceptable level at the receiver-input terminals.

The circuits feature individual strobe inputs for each channel and a strobe input common to both channels for logic versatility. The strobe inputs are tested to ensure 400 mV of dc noise margin when interfaced with Series 54/74 TTL.

The circuits feature high input impedance and low input currents, which induce very little loading on the transmission line. This makes these devices especially useful in party-line systems. The excellent input sensitivity (3 mV typical) is particularly important when data is to be detected at the end of a long transmission line and the amplitude of the data has deteriorated due to cable losses. The circuits are designed to detect input signals of 10-mV (or greater) amplitude and convert the polarity of the signal into appropriate TTL-compatible output logic levels.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC+} (see Note 1)	
Supply voltage, V _{CC} (see Note 1)	7 V
Differential input voltage, VID (see Note 2)	±6 V
Common-mode input voltage, V _{IC} (see Note 3)	±5 V
Strobe input voltage	5.5 V
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: A. All voltage values, except differential voltages, are with respect to GND terminal.

- 1. Differential input voltage values are at the noninverting (A) terminal with respect to the inverting (B) terminal.
- 2. Common-mode input voltage is the average of the voltages at the A and B inputs.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING FACTOR	T _A = 70°C
	POWER RATING	ABOVE T _A = 25°C	POWER RATING
N	1050 mW	9.2 mW/°C	636 mW



recommended operating conditions (see Note 4)

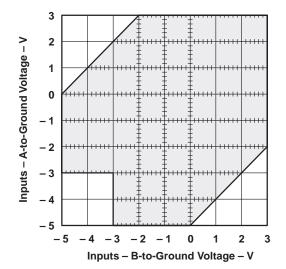
	MIN	NOM MAX	UNIT
Supply voltage, V _{CC+}	4.75	5 5.25	V
Supply voltage, V _{CC} _	-4.75	-5 -5.25	V
High-level differential input voltage, VID(H) (see Note 5)	0.01	5	V
Low-level differential input voltage, VID(L)	-5†	-0.01	V
Common-mode input voltage, VIC (see Notes 5 and 6)	-3†	3	V
Input voltage, any differential input to ground (see Note 5)	-5†	3	V
High-level input voltage at strobe inputs, VIH(S)	2	5.5	V
Low-level input voltage at strobe inputs, VIL(S)	0	0.8	V
Low-level output current, IOL		-16	mA
Operating free-air temperature, T _A	0	70	°C

[†] The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic voltage levels only.

NOTES: B. When using only one channel of the line receiver, the strobe G of the unused channel should be grounded and at least one of the differential inputs of the unused receiver should be terminated at some voltage between -3 V and 3 V.

3. The recommended combinations of input voltages fall within the shaded area of the figure shown.

4. The common-mode voltage may be as low as -4 V provided that the more positive of the two inputs is not more negative than -3 V.





electrical characteristics over recommended free-air temperature range (unless otherwise noted)

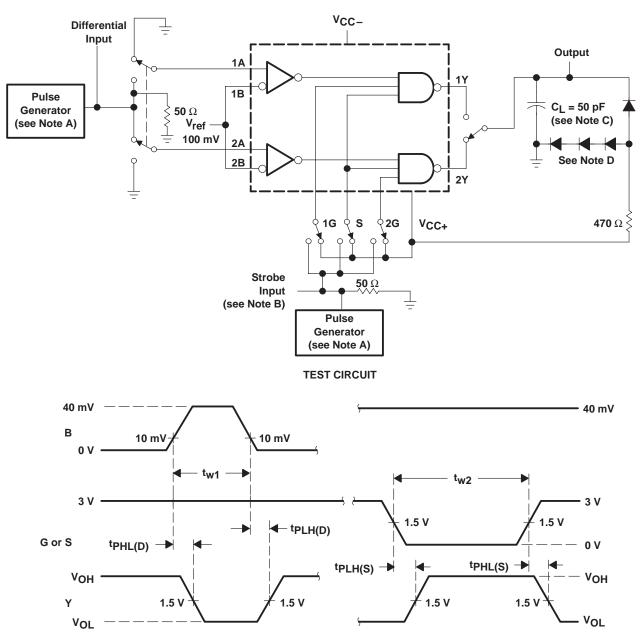
	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT	
I _{IH}	High-level input current	$V_{CC\pm} = \pm 5.25 V$		$V_{ID} = -5 V$		30	75	μΑ
۱ _{IL}	Low-level input current	$V_{CC\pm} = \pm 5.25 V$		V _{ID} = 5 V			-10	μΑ
	High-level input current	$V_{CC\pm} = \pm 5.25 V$,	V _{IH(S)} = 2.4 V				40	μΑ
ΙΗ	into 1G or 2G	$V_{CC\pm} = \pm 5.25 \text{ V},$	V _{IH(S)} = ± 5.25 V				1	mA
ΙL	Low-level input current into 1G or 2G	$V_{CC\pm} = \pm 5.25 V,$	$V_{IL(S)} = 0.4 V$				-1.6	mA
1	High-level input current into S	$V_{CC\pm} = \pm 5.25$ V,	VIH(S) = 2.4 V				80	μΑ
ΙΗ	High-level input current into S	$V_{CC\pm} = \pm 5.25 V,$	VIH(S) = ± 5.25 V				2	mA
١ _{IL}	Low-level input current into S	$V_{CC\pm} = \pm 5.25 V,$	$V_{IL(S)} = 0.4 V$				-3.2	mA
VOH	High-level output voltage	$V_{CC\pm} = \pm 4.75 V,$ $I_{OH} = -400 \ \mu A,$	V _{IL(S)} = 0.8 V, V _{IC} = -3 V to 3 V	$V_{ID(H)} = 10 \text{ mV},$	2.4			V
VOL	Low-level output voltage	$V_{CC\pm} = \pm 4.75 \text{ V},$ $I_{OL} = 16 \text{ mA},$	VIH(S) = 2 V, V _{IC} = −3 V to 3 V	$V_{ID(L)} = -10 \text{ mV},$			0.4	V
IOH	High-level output current	$V_{CC\pm} = \pm 4.75$ V,	$V_{OH} = \pm 5.25 V$				400	μΑ
IOS	Short-circuit output current [‡]	$V_{CC\pm} = \pm 5.25 V$			-18		-70	mA
ICC+	Supply current from V_{CC+}	$V_{CC\pm} = \pm 5.25 V,$	$T_A = 25^{\circ}C$,	Outputs high		18	30	mA
ICC-	Supply current from V _{CC} _	$V_{CC\pm} = \pm 5.25 V,$	T _A = 25°C,	Outputs high		-8.4	-15	mA

[†] All typical values are at $V_{CC+} = 5 \text{ V}$, $V_{CC-} = -5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. [‡] Not more than one output should be shorted at a time.

switching characteristics, $V_{CC+} = 5 V$, $V_{CC-} = -5 V$, $T_A = 25^{\circ}C$

	PARAMETER TEST CONDITIONS			MIN	МАХ	UNIT
^t PLH(D)	Propagation delay time, low- to high-level output, from differ- ential inputs A and B	R _L = 470 Ω, See Figure 1			35	ns
^t PHL(D)	Propagation delay time, high- to low-level output, from differ- ential inputs A and B		C _L = 50 pF,		20	ns
^t PLH(S)	Propagation delay time, low- to high-level output, from strobe input G or S				17	ns
^t PHL(S)	Propagation delay time, high- to low-level output, from strobe input G or S				17	ns





PARAMETER MEASUREMENT INFORMATION

VOLTAGE WAVEFORMS

NOTES: A. The pulse generators have the following characteristics: $Z_0 = 50 \Omega$, $t_f \le 5 ns$, $t_{W1} = 500 ns$ with PRR = 1 MHz, $t_{W2} = 1 \mu s$ with PRR = 500 kHz.

B. Strobe input pulse is applied to Strobe 1G when inputs 1A-1B are being tested, to Strobe S when inputs 1A-1B or 2A-2B are being tested, and to Strobe 2G when inputs 2A-2B are being tested.

- C. CL includes probe and jig capacitance.
- D. All diodes are 1N916.

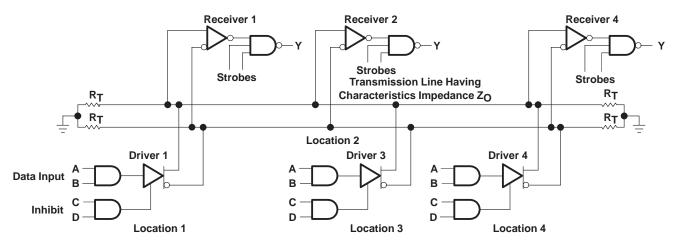




Strobes Ŧ **100** Ω Input Output From SN75361A То to TTL TTL < **MOS Memory** or Dummy SN75452B Line Ş **100** Ω '207B Vref Adjustment Drive Memory Sense

APPLICATION INFORMATION

Figure 2. MOS Memory Sense Amplifier



Receivers are SN75207B; drivers are SN55109A, SN55110A, SN75110A, or SN75112.

Figure 3. Data-Bus or Parity-Line System

PRECAUTIONS: When only one receiver in a package is being used, at least one of the differential inputs of the unused receiver should be terminated at some voltage between -3 V and 3 V, preferably at GND. Failure to do so will cause improper operation of the unit being used because of common bias circuitry for the current sources of the two receivers. Strobe G of the unused channel should be grounded.



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated